

# 2SB1070, 2SB1070A

## Silicon PNP epitaxial planar type

For low-voltage switching

### ■ Features

- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- High-speed switching
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment

### ■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	2SB1070	$V_{CBO}$	-40	V
	2SB1070A		-50	
Collector-emitter voltage (Base open)	2SB1070	$V_{CEO}$	-20	V
	2SB1070A		-40	
Emitter-base voltage (Collector open)	$V_{EBO}$	-5	V	
Collector current	$I_C$	-4	A	
Peak collector current	$I_{CP}$	-8	A	
Collector power dissipation	$P_C$	25	W	
		$T_a = 25^\circ\text{C}$		1.3
Junction temperature	$T_j$	150	$^\circ\text{C}$	
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$	

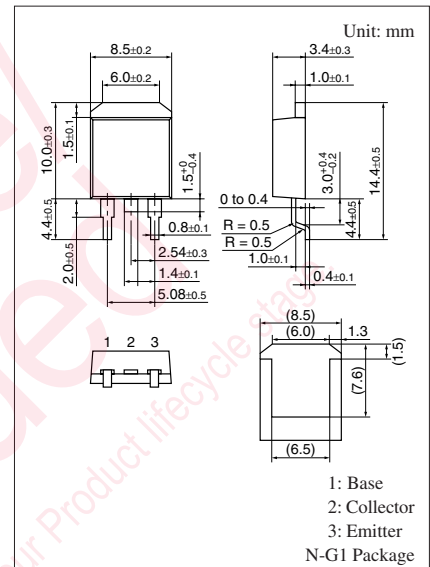
### ■ Electrical Characteristics $T_C = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	2SB1070	$I_C = -10 \text{ mA}, I_B = 0$	-20			V
	2SB1070A		-40			
Collector-base cutoff current (Emitter open)	2SB1070	$V_{CB} = -40 \text{ V}, I_E = 0$			-50	$\mu\text{A}$
	2SB1070A	$V_{CB} = -50 \text{ V}, I_E = 0$			-50	
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = -5 \text{ V}, I_C = 0$			-50	$\mu\text{A}$
Forward current transfer ratio	$h_{FE1}$	$V_{CE} = -2 \text{ V}, I_C = -0.1 \text{ A}$	45			—
	$h_{FE2}^*$	$V_{CE} = -2 \text{ V}, I_C = -1 \text{ A}$	90	260		
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -2 \text{ A}, I_B = -0.1 \text{ A}$			-1.5	V
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2 \text{ A}, I_B = -0.1 \text{ A}$			-0.5	V
Transition frequency	$f_T$	$V_{CE} = -5 \text{ V}, I_C = -0.5 \text{ A}, f = 10 \text{ MHz}$		150		MHz
Turn-on time	$t_{on}$	$I_C = -2 \text{ A}$		0.3		$\mu\text{s}$
Storage time	$t_{stg}$	$I_{B1} = -0.2 \text{ A}, I_{B2} = 0.2 \text{ A}$		0.4		$\mu\text{s}$
Fall time	$t_f$	$V_{CC} = -20 \text{ V}$		0.1		$\mu\text{s}$

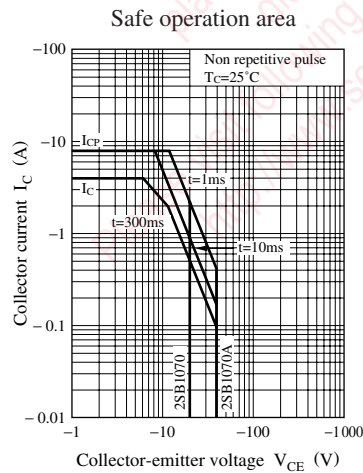
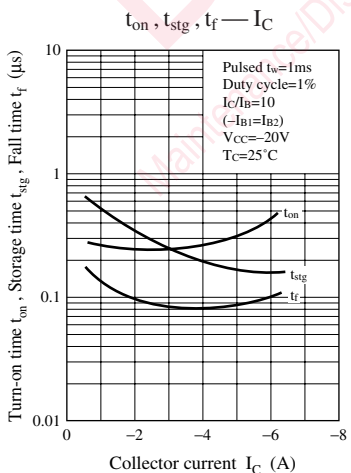
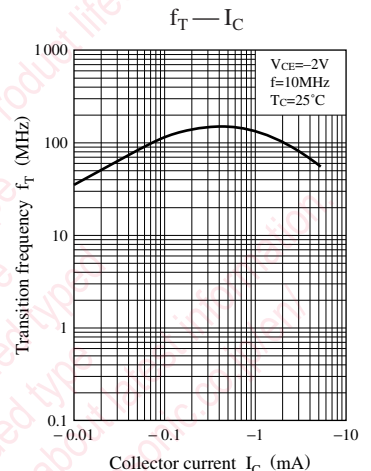
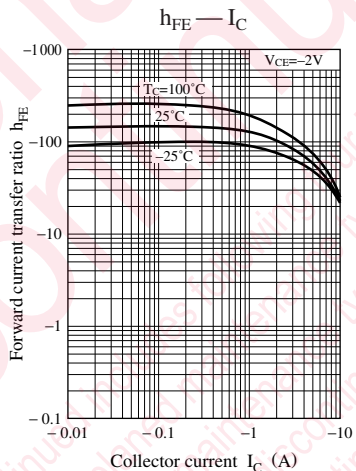
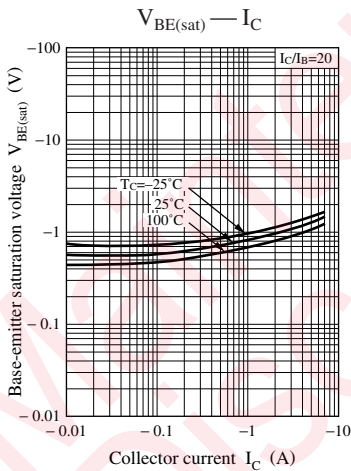
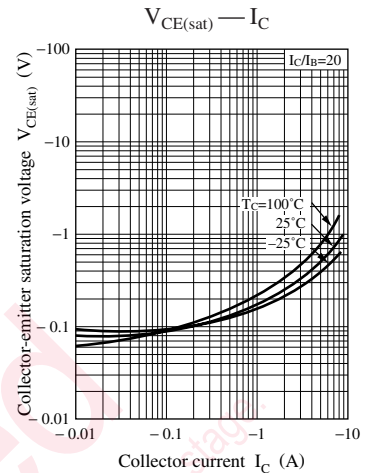
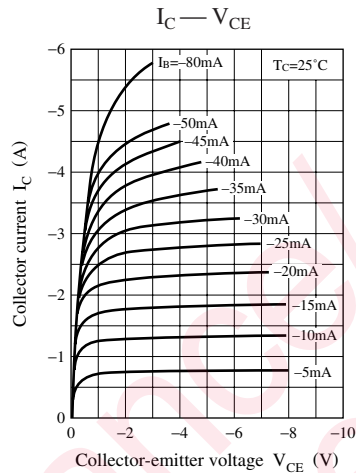
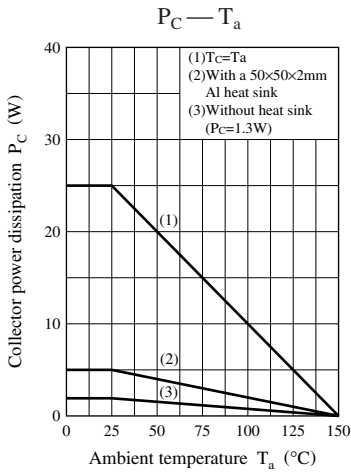
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

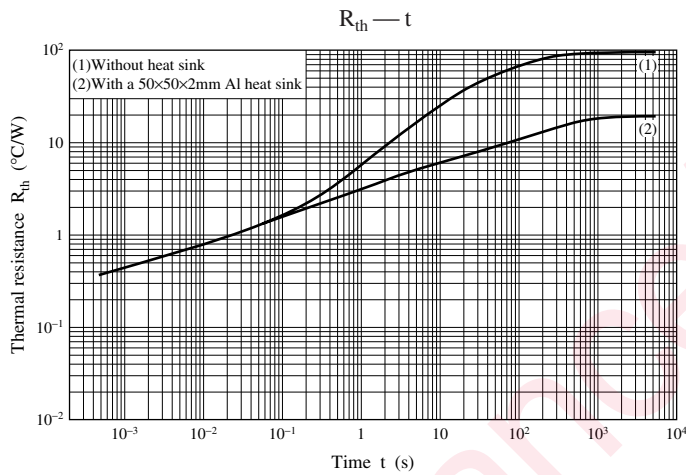
2. \*: Rank classification

Rank	Q	P
$h_{FE2}$	90 to 180	130 to 260



Note) Self-supported type package is also prepared.





Maintenance/Discontinued

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 planned maintenance type  
 maintenance type  
 planned discontinued type  
 discontinued type  
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